

Toshiba Intelligent Power Device Silicon Monolithic MOS Integrated Circuit

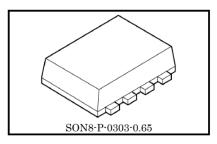
TPD1054F

Low-Side Switch for Solenoid, Mechanical relay and Lamp Drive

1. Description

TPD1054F is a low-side switch.

The IC has a MOSFET (D-MOS) output which can be directly driven from a CMOS or TTL logic circuit (e.g., an MPU). This IC is a monolithic power IC with intelligent features of protection and diagnostic functions.



Weight: 0.017 g (typ.)

2. Applications

Solenoid drive, mechanical relay drive and lamp drive.

3. Features

- A monolithic power IC with a structure combining a control block and a power MOSFET (D-MOS) on single chip.
- Can directly drive a power load from a CMOS or TTL logic (5 V, 3.3 V input compatible).
- Built-in overcurrent (Load short circuit), overtemperature (Thermal shutdown) and overvoltage (Active clamp) protection circuits.
- Incorporates a diagnosis function that allows diagnosis output to be read externally at overcurrent (load short circuit), overtemperature or load opening.
- Low Drain-Source ON-resistance:

```
R_{DS(ON)} = 0.8 \Omega \text{ (max)} (@V_{DD} = 5 \text{ V}, V_{STBY} = 5 \text{ V}, V_{IN} = 5 \text{ V}, I_{O} = 0.5 \text{ A}, T_{ch} = 25 ^{\circ}\text{C})
```

Low Leakage Current:

```
I_{DD1} = 10 \ \mu A \ (max) \ (@V_{IN} = 0 \ V, \ V_{STBY} = 0 \ V, \ V_{DD} = 5 \ V, \ T_{ch} = -40 \ to \ 125 \ ^{\circ}C) I_{OL} = 10 \ \mu A \ (max) \ (@V_{IN} = 0 \ V, \ V_{STBY} = 0 \ V, \ V_{DD} = 5 \ V, \ V_{OUT} = 8 \ to \ 16 \ V, \ T_{ch} = -40 \ to \ 125 \ ^{\circ}C)
```

- AEC-Q100 qualified.
- It is a surface-mounted package "PS-8" (named by Toshiba), and the packing is embossed-tape packing.

Note: Due to its MOS structure. This product is sensitive to static electricity.

Start of commercial production 2013-12



4. Block Diagram

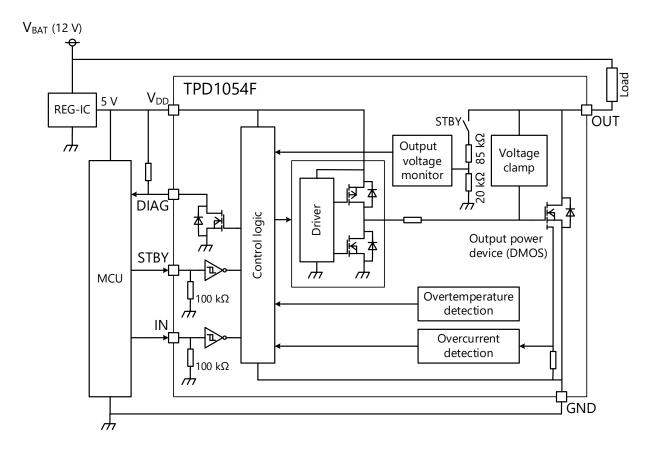


Figure 4.1 Block Diagram

Note: Numerical values in the block diagram are typical values.

5. Pin Assignments

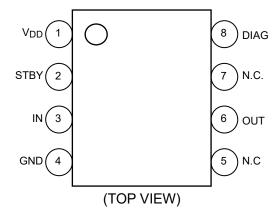


Figure 5.1 Pin Assignments



6. Pin Description

Table 6.1 Pin Description

Pin No.	Symbol	I/O	Pin Description
1	V_{DD}	_	Power supply pin.
2	STBY	IN	STBY pin. V _{STBY} =L/Open: I _{DD} ≤10 µA (Standby mode) V _{STBY} =H:Active control
3	IN	IN	Input pin. The IN pin has an internal pull-down resistor. Even if the IN pin is open, the output will not accidentally turn on.
4	GND	_	Ground pin.
5	N.C	_	No-Connect pin. (Not connected to the chip.)
6	OUT	OUT	Output pin. When a load short-circuit causes an overcurrent (1.0A min) to flow into a device, output current is limited in order to protect the IC.
7	N.C	_	No-Connect pin. (Not connected to the chip.)
8	DIAG	OUT	Diagnosis detection pin. It is open drain composition. When Input is "H" (Output on), and Overcurrent or Overtemperature is detected, DIAG becomes low level and it is latched. When input is low level, the state of latch is reset. When Input is "L" (Output off), the output is disconnected (load open is detected), V _{DIAG} =H output.



7. Functional Description

7.1. Timing chart

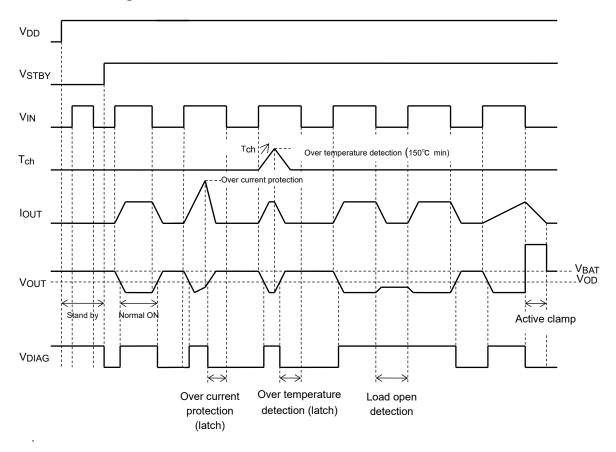


Figure 7.1 Timing chart

7.2. Truth table

Table 7.1 Truth table

STBY	IN	Output DMOS state	Output voltage Vout (Note 1)		Operating state		
L	L	OFF	Н	Н	Standby made		
L	Н	OFF	Н	Н	Standby mode		
Н	L	OFF	Н	L	Normal OFF		
Н	Н	ON	L	Н	Normal ON		
Н	Н	OFF (latch*)	Н	L (latch*)	Overcurrent (load short)		
Н	Н	OFF (latch*)	Н	L (latch*)	Over temperature		
Н	L	OFF	L	Н	Load open (output is disconnected)		

Note 1: H state is V_{OUT}>=V_{OD}. L state is V_{OUT}<V_{OD}.

^{*}Latch reset condition: VSTBY<VIL or VSTBY<VIL.



8. Absolute Maximum Ratings (Note)

Table 8.1 Absolute Maximum Ratings

(T_a = 25°C unless otherwise specified)

			(1a 20 0 dimest editer mee speemen)				
Characteristics	Symbol	PIN	Rating	Unit	Note		
Supply voltage	V_{DD}	V_{DD}	-0.3 to 6.0	V	-		
Input voltage	V _{IN} , V _{STBY}	IN, STBY	-0.3 to 6.0	V	-		
Diagnosis output voltage	V _{DIAG}	DIAG	-0.3 to 6.0	V	-		
Diagnosis output current	IDIAG	DIAG	5.0	mA	-		
Output voltage	V _{OUT}	OUT	-0.3 to 40.0	V	-		
Output current	I _{OUT}	OUT	Internally Limited	Α	-		
Dower discipation	P _{D(1)}	-	0.70	W	Refer to Figure 9.1		
Power dissipation	P _{D(2)}	-	0.35	W	Refer to Figure 9.2		
Single pulse active clamp capability (Note 1)	E _{AS}	-	125	mJ	-		
Active clamp current	I _{AR}	-	1.0	Α	-		
Operating temperature	T _{opr}	-	-40 to 125	°C	-		
Channel temperature	T _{ch}	-	150	°C	-		
Storage temperature	T _{stg}	-	-55 to 150	°C	-		

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

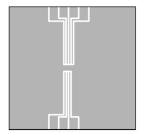
Note 1: Active clamp capability (single pulse) test condition VBAT=40 V, Tch=25°C (initial), L=50 mH, IAR=1 A

9. Thermal Characteristics

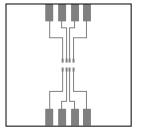
Table 9.1 Thermal characteristics

Characteristics	Symbol Max		Unit
Thermal resistance, channel to ambient	D.,	178.6 (Figure 9.1)	°C/W
Thermal resistance, charmer to ambient	R _{th (ch-a)}	357.2 (Figure 9.2)	C/VV

 $P_D = (T_{ch} - T_a) / R_{th (ch-a)}$



Glass epoxy board Material: FR-4 25.4 mm × 25.4 mm × 0.8 mm



Glass epoxy board Material: FR-4 25.4 mm × 25.4 mm × 0.8 mm

Figure 9.1 Glass epoxy board (a)

Figure 9.2 Glass epoxy board (b)



10. Operating Ranges

Table 10.1 Operating Ranges

Characteristics	Symbol	Pin	Condition	Min	Тур.	Max	Unit
Drain-source clamp voltage	V _{(CL) DSS}	OUT	I _O =1 mA, V _{STBY} =5 V, V _{IN} =0 V	40	45	50	V
Operating supply voltage	V _{DD (opr)}	V_{DD}	-	4.5	5.0	5.5	V

11. Electrical Characteristics

Table 11.1 Electrical Characteristics

(Unless otherwise specified T_{ch} = -40 to 125 °C, V_{DD} = 4.5 to 5.5 V)

Characteristics	Symbol	Pin	Test circuit	Test condition	Min	Typ.	Max	Unit
	I _{DD1}	V_{DD}	-	V _{STBY} =0 V, V _{IN} =0 V, V _{DD} =5 V	-	-	10	μΑ
Supply current	I _{DD2}	V _{DD}	-	V _{STBY} =5 V, V _{IN} =0 V, V _{DD} =5 V	-	0.5	2.0	mA
	I _{DD3}	V _{DD}	-	V _{STBY} =5 V, V _{IN} =5 V, V _{DD} =5 V	-	0.5	2.0	mA
Output leakage current	I _{OL1}	OUT	-	V _{STBY} =V _{IL} , V _{IN} =V _{IL} , V _{OUT} =8 to 16 V		-	10	μA
Output leakage current	I _{OL2}	OUT	-	V _{STBY} =V _{IH} , V _{IN} =V _{IL} , V _{OUT} =8 to 16 V	-	120	300	μA
High level input voltage	V _{IH}	IN,STBY	-	-	2.3	-	-	V
Low level input voltage	V _{IL}	IN,STBY	-	-	-	-	0.8	V
High level input current	l _{IH}	IN,STBY	-	V _{IN} (V _{STBY})=5 V, V _{DD} =5 V	-	-	200	μA
Low level input current	l₁∟	IN,STBY	-	V _{IN} (V _{STBY})=0 V, V _{DD} =5 V	-1	-	1	μΑ
Diagnosis output voltage	V_{DL}	DIAG	-	I _{DIAG} =1 mA	ı	0.1	0.5	V
Diagnosis output current	I _{DH}	DIAG	-	V _{DIAG} =5.5 V	·	-	10	μΑ
Drain-source	R _{DS(ON)1}	OUT	ı	I _O =+0.5 A, T _{ch} =25 °C, V _{DD} =5 V, V _{STBY} =V _{IH} , V _{IN} =V _{IH}	ı	0.45	0.80	Ω
ON-resistance	R _{DS(ON)2}	OUT	-	I _O =+0.5 A, T _{ch} =-40 to 125 °C, V _{DD} =5 V, V _{STBY} =V _{IH} , V _{IN} =V _{IH}	1	-	1.2	Ω
Overtemperature detection	T _{OT}	-	-	V _{STBY} =5 V, V _{IN} =5 V,	150	175	200	°C
Overcurrent detection	loc	OUT	-	V _{STBY} =5 V, V _{IN} =5 V,	1.0	2.2	3.5	Α
Load open	R _{OP}	OUT	-	V_{STBY} =5 V, V_{IN} =0 V, V_{BAT} =8 to 16 V	10	300	1000	kΩ
threshold resistance	⊿Rop	OUT	-	V _{STBY} =5 V, V _{IN} =0 V, V _{BAT} =8 to 16 V	ı	30	-	kΩ
Diagnosis output	V _{OD}	OUT	-	V _{STBY} =5 V	2	3	4	V
threshold voltage	∠Vod	OUT	-	V _{STBY} =5 V	ı	0.3	-	V
OUT-GND	R _{OUT1}	OUT	-	V _{STBY} =5 V, V _{IN} =0 V, T _{ch} =25 °C	50	105	170	kΩ
internal resistance	R _{OUT2}	OUT	-	V _{STBY} =5 V, V _{IN} =0 V, T _{ch} =-40 to 125 °C	40	105	200	kΩ
Switching time	t _{on}	OUT	1	$V_{STBY}=5$ V, $V_{IN}=0\rightarrow5$ V, $V_{DD}=5$ V, $T_{ch}=25$ °C, $V_{BAT}=12$ V, $R_{L}=60$ Ω	-	0.5	1	μs
Owntorning unite	t _{off}	OUT	1	$V_{STBY}=5$ V, $V_{IN}=5\rightarrow0$ V, $V_{DD}=5$ V, $T_{ch}=25$ °C, $V_{BAT}=12$ V, $R_{L}=60$ Ω	ı	0.5	1	μs

Note 1: The condition of the typical value is $T_{ch}=25^{\circ}C$, $V_{DD}=5V$.



12. Test Circuit

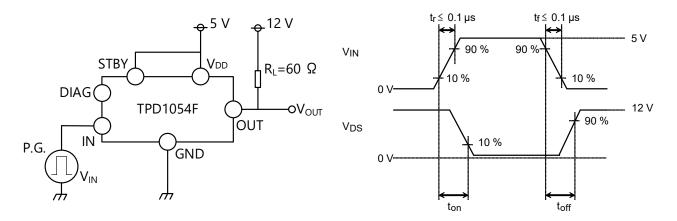


Figure 12.1 Test circuit 1 (Switching time test circuit)

Figure 12.2 Switching time waveforms



13. Characteristic curves

Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

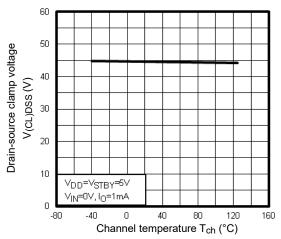


Figure 13.1 V_{(CL)DSS} – T_{ch}

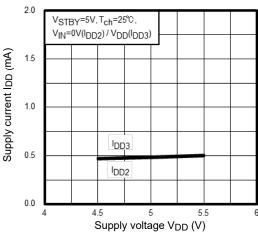


Figure 13.2 I_{DD} – V_{DD}

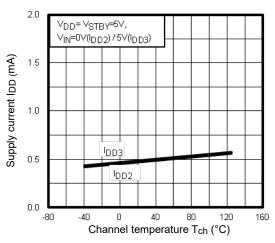
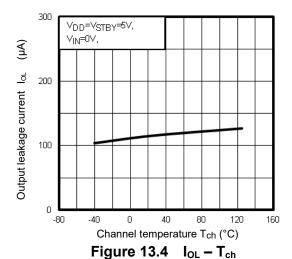


Figure 13.3 I_{DD} - T_{ch}





8

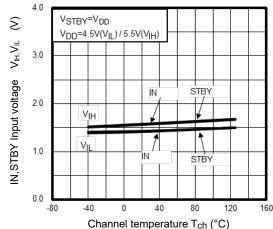


Figure 13.6 V_{IH}, V_{IL} - T_{ch}

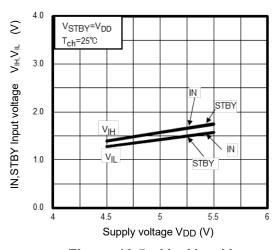


Figure 13.5 V_{IH}, V_{IL} - V_{DD}



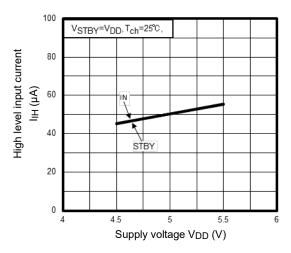


Figure 13.7 I_{IH} -V_{DD}

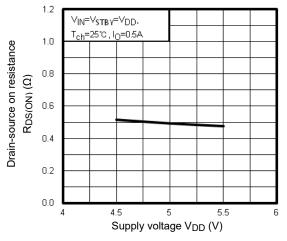


Figure 13.9 $R_{DS(ON)} - V_{DD}$

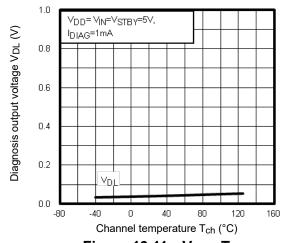


Figure 13.11 V_{DL} – T_{ch}

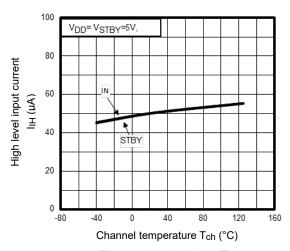


Figure 13.8 I_{IH} – T_{ch}

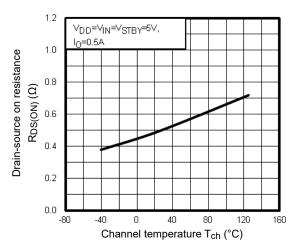


Figure 13.10 $R_{DS(ON)} - T_{ch}$

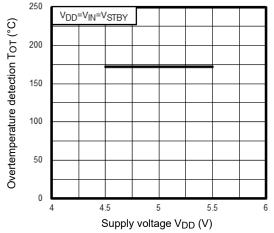


Figure 13.12 $T_{OT} - V_{DD}$



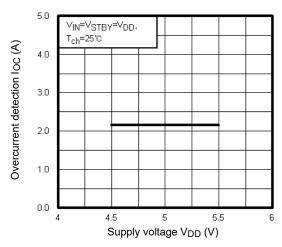
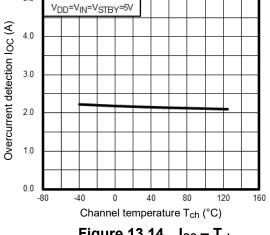


Figure 13.13 I_{OC} - V_{DD}



5.0

Figure 13.14 I_{oc} – T_{ch}

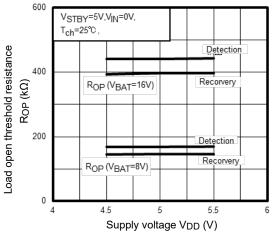


Figure 13.15 $R_{OP} - V_{DD}$

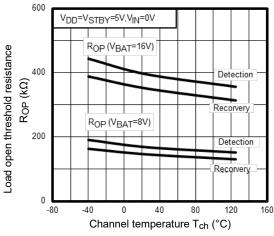


Figure 13.16 R_{OP} - T_{ch}

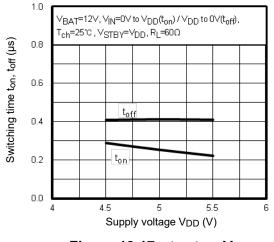


Figure 13.17 t_{on} , $t_{off} - V_{DD}$

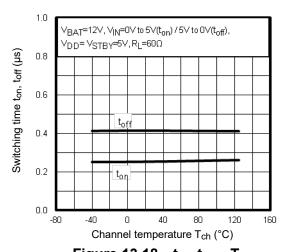


Figure 13.18 t_{on} , $t_{off} - T_{ch}$



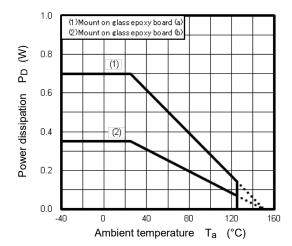


Figure 13.19 $P_D - T_a$



14. Package Information

14.1. Package Dimensions

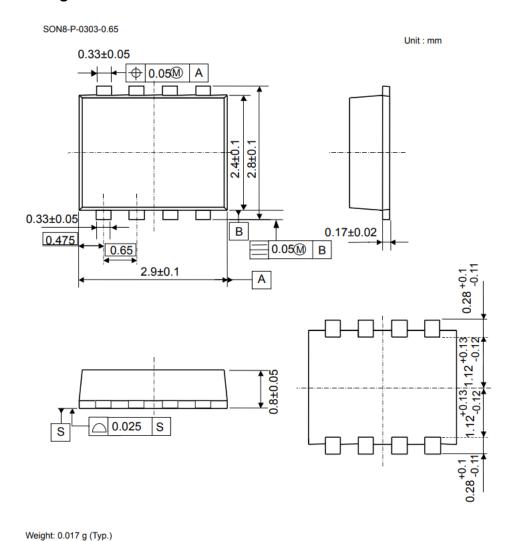


Figure 14.1 Package Dimensions



14.2. Marking

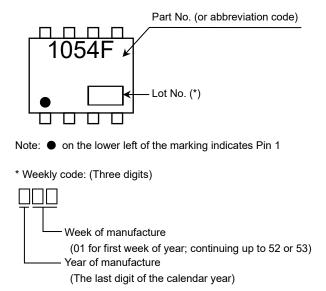


Figure 14.2 Marking

14.3. Land Pattern Dimensions for Reference only

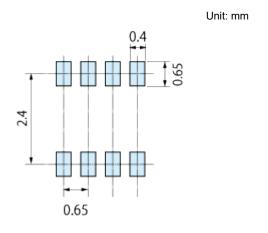


Figure 14.3 Land Pattern Dimensions for Reference only



15. IC Usage Considerations

15.1. Notes on Handling of ICs

The absolute maximum ratings of a semiconductor device are a set of ratings that must not be exceeded, even for a moment. None of the multiple ratings can be exceeded. Exceeding the absolute maximum ratings may cause destruction, damage and deterioration, and may result in injury due to explosion or burning.



RESTRICTIONS ON PRODUCT USE

Toshiba Corporation and its subsidiaries and affiliates are collectively referred to as "TOSHIBA". Hardware, software and systems described in this document are collectively referred to as "Product".

- TOSHIBA reserves the right to make changes to the information in this document and related Product without notice.
- This document and any information herein may not be reproduced without prior written permission from TOSHIBA. Even with TOSHIBA's written permission, reproduction is permissible only if reproduction is without alteration/omission.
- Though TOSHIBA works continually to improve Product's quality and reliability, Product can malfunction or fail. Customers are responsible for complying with safety standards and for providing adequate designs and safeguards for their hardware, software and systems which minimize risk and avoid situations in which a malfunction or failure of Product could cause loss of human life, bodily injury or damage to property, including data loss or corruption. Before customers use the Product, create designs including the Product, or incorporate the Product into their own applications, customers must also refer to and comply with (a) the latest versions of all relevant TOSHIBA information, including without limitation, this document, the specifications, the data sheets and application notes for Product and the precautions and conditions set forth in the "TOSHIBA Semiconductor Reliability Handbook" and (b) the instructions for the application with which the Product will be used with or for. Customers are solely responsible for all aspects of their own product design or applications, including but not limited to (a) determining the appropriateness of the use of this Product in such design or applications; (b) evaluating and determining the applicability of any information contained in this document, or in charts, diagrams, programs, algorithms, sample application circuits, or any other referenced documents; and (c) validating all operating parameters for such designs and applications. TOSHIBA ASSUMES NO LIABILITY FOR CUSTOMERS' PRODUCT DESIGN OR APPLICATIONS.
- PRODUCT IS NEITHER INTENDED NOR WARRANTED FOR USE IN EQUIPMENTS OR SYSTEMS THAT REQUIRE EXTRAORDINARILY HIGH LEVELS OF QUALITY AND/OR RELIABILITY, AND/OR A MALFUNCTION OR FAILURE OF WHICH MAY CAUSE LOSS OF HUMAN LIFE, BODILY INJURY, SERIOUS PROPERTY DAMAGE AND/OR SERIOUS PUBLIC IMPACT ("UNINTENDED USE"). Except for specific applications as expressly stated in this document, Unintended Use includes, without limitation, equipment used in nuclear facilities, equipment used in the aerospace industry, lifesaving and/or life supporting medical equipment, equipment used for automobiles, trains, ships and other transportation, traffic signaling equipment, equipment used to control combustions or explosions, safety devices, elevators and escalators, and devices related to power plant. IF YOU USE PRODUCT FOR UNINTENDED USE, TOSHIBA ASSUMES NO LIABILITY FOR PRODUCT. For details, please contact your TOSHIBA sales representative or contact us via our
- Do not disassemble, analyze, reverse-engineer, alter, modify, translate or copy Product, whether in whole or in part.
- Product shall not be used for or incorporated into any products or systems whose manufacture, use, or sale is prohibited under any applicable laws or regulations.
- The information contained herein is presented only as guidance for Product use. No responsibility is assumed by TOSHIBA for any infringement of patents or any other intellectual property rights of third parties that may result from the use of Product. No license to any intellectual property right is granted by this document, whether express or implied, by estoppel or otherwise.
- ABSENT A WRITTEN SIGNED AGREEMENT, EXCEPT AS PROVIDED IN THE RELEVANT TERMS AND CONDITIONS OF SALE FOR PRODUCT, AND TO THE MAXIMUM EXTENT ALLOWABLE BY LAW, TOSHIBA (1) ASSUMES NO LIABILITY WHATSOEVER, INCLUDING WITHOUT LIMITATION, INDIRECT, CONSEQUENTIAL, SPECIAL, OR INCIDENTAL DAMAGES OR LOSS, INCLUDING WITHOUT LIMITATION, LOSS OF PROFITS, LOSS OF OPPORTUNITIES, BUSINESS INTERRUPTION AND LOSS OF DATA, AND (2) DISCLAIMS ANY AND ALL EXPRESS OR IMPLIED WARRANTIES AND CONDITIONS RELATED TO SALE, USE OF PRODUCT, OR INFORMATION, INCLUDING WARRANTIES OR CONDITIONS OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE, ACCURACY OF INFORMATION, OR NONINFRINGEMENT.
- Do not use or otherwise make available Product or related software or technology for any military purposes, including without limitation, for the design, development, use, stockpiling or manufacturing of nuclear, chemical, or biological weapons or missile technology products (mass destruction weapons). Product and related software and technology may be controlled under the applicable export laws and regulations including, without limitation, the Japanese Foreign Exchange and Foreign Trade Law and the U.S. Export Administration Regulations. Export and re-export of Product or related software or technology are strictly prohibited except in compliance with all applicable export laws and regulations.
- Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. Please use Product in compliance with all applicable laws and regulations that regulate the inclusion or use of controlled substances, including without limitation, the EU RoHS Directive. TOSHIBA ASSUMES NO LIABILITY FOR DAMAGES OR LOSSES OCCURRING AS A RESULT OF NONCOMPLIANCE WITH APPLICABLE LAWS AND REGULATIONS.

Toshiba Electronic Devices & Storage Corporation

https://toshiba.semicon-storage.com/